

BCR16PM-12LC

Triac

Medium Power Use

REJ03G1262-0200 Rev.2.00 Jul 28, 2006

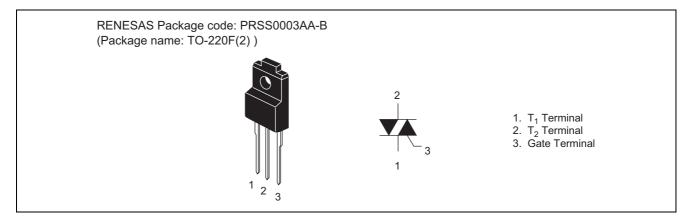
Features

• I_{FGTI}, I_{RGTI}, I_{RGTIII}: 50 mA

• Viso: 1500 V

- The product guaranteed maximum junction temperature 150°C.
- Insulated Type
- Planar Passivation Type

Outline



Applications

Motor control, heater control

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	700	V

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Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	16	А	Commercial frequency, sine full wave 360° conduction, Tc = 60°C
Surge on-state current	I _{TSM}	96	А	60Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	38	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	
Mass	_	2.0	g	Typical value
Isolation voltage	Viso	1500	V	Ta = 25°C, AC 1 minute, $T_1 \cdot T_2 \cdot G$ terminal to case

Notes: 1. Gate open.

Electrical Characteristics

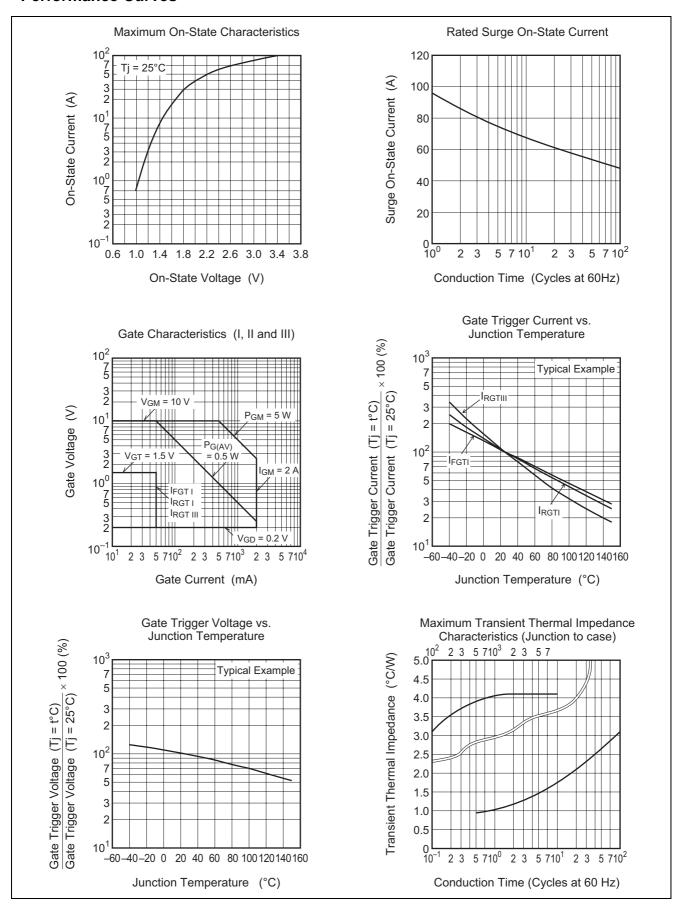
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions	
Repetitive peak off-state current		I _{DRM}	_	_	2.0	mA	Tj = 125°C, V _{DRM} applied	
On-state voltage		V_{TM}	_	_	1.75	V	Tc = 25°C, I _{TM} = 25 A, Instantaneous measurement	
Gate trigger voltage ^{Note2}	I	V_{FGTI}		_	1.5	V	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,	
	II	V_{RGTI}		_	1.5	V	$R_G = 330 \Omega$	
	III	V_{RGTIII}		_	1.5	V		
Gate trigger current ^{Note2}	I	I _{FGTI}	_	_	50	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,	
	II	I_{RGTI}			50	mA	$R_G = 330 \Omega$	
	III	I_{RGTIII}		_	50	mA		
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	$Tj = 125$ °C, $V_D = 1/2 V_{DRM}$	
Thermal resistance		R _{th (j-c)}	_	_	4.1	°C/W	Junction to case ^{Note3}	
Critical-rate of rise of off-state commutating voltage Note4		(dv/dt)c	10	_	_	V/μs	Tj = 125°C	

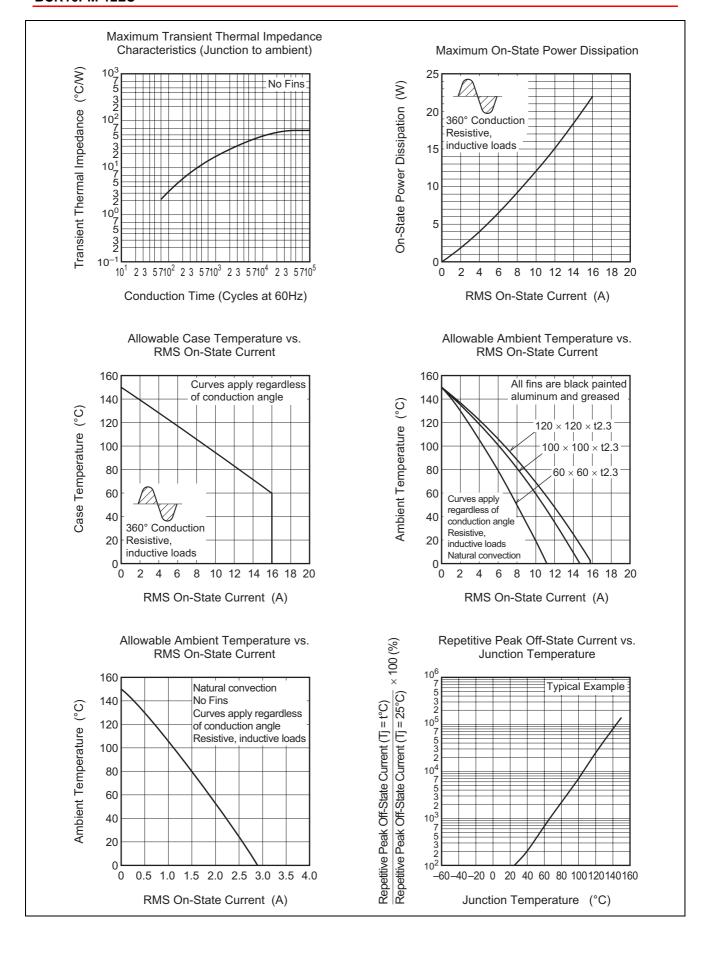
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

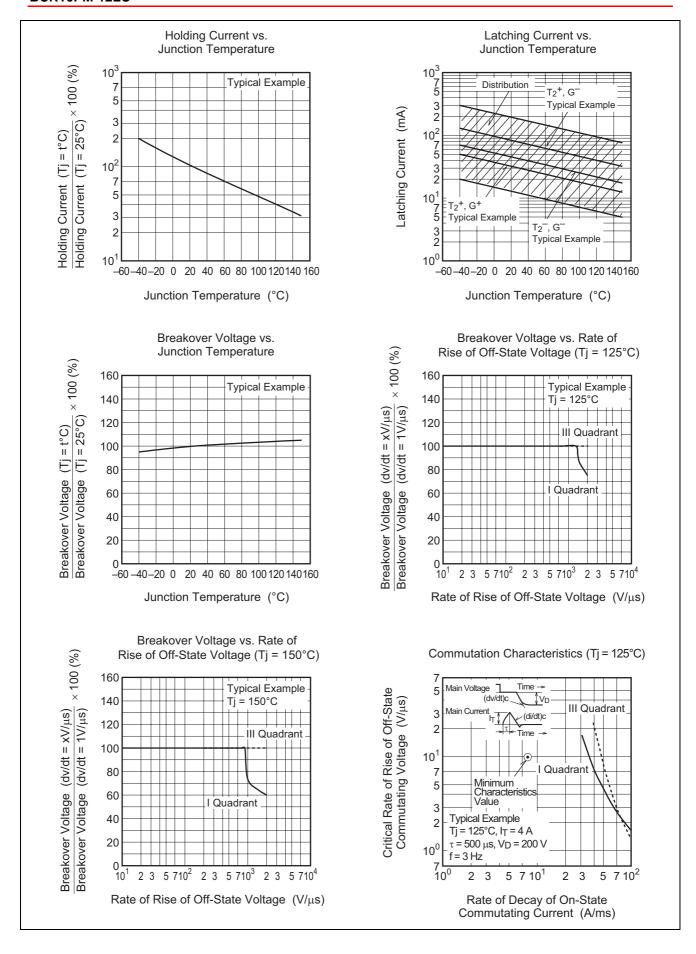
- 3. The contact thermal resistance $R_{th\ (c\text{-}f)}$ in case of greasing is 0.5°C/W.
- 4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

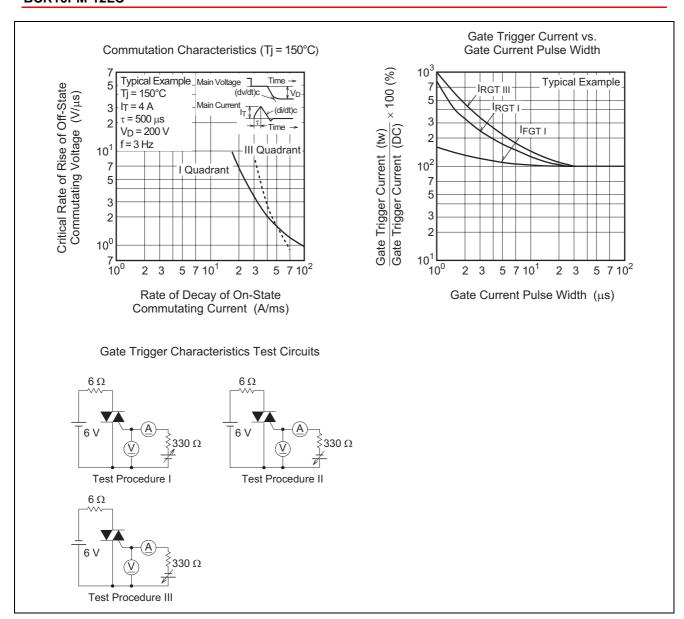
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125°C	Supply Voltage → Time
2. Rate of decay of on-state commutating current (di/dt)c = - 8 A/ms	Main Current (di/dt)c Time
3. Peak off-state voltage $V_D = 400 \text{ V}$	Main Voltage Time (dv/dt)c

Performance Curves

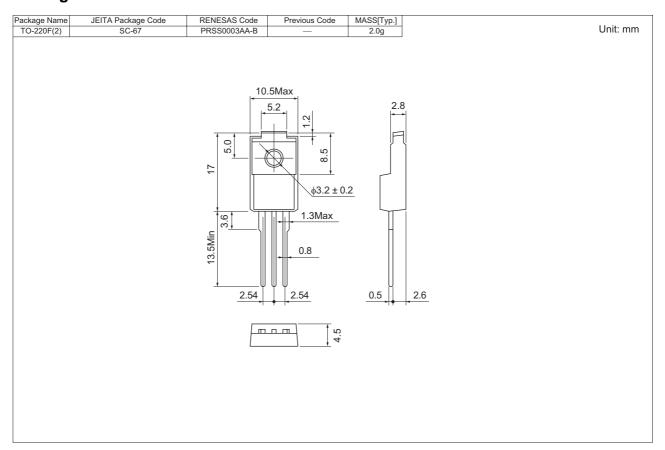








Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	100	Type name	BCR16PM-12LC
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	BCR16PM-12LC-A8

Note: Please confirm the specification about the shipping in detail.

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